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all-anti-Octasilane: Conformation Control of Silicon Chains Using the Bicyclic Trisilane as a Building Block

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Structure control of flexible linear chains is of fundamental importance for optimizing the physical properties of organic and organometallic polymers. Linear polysilanes are the most typical one-dimensional polymers and show remarkable photophysical and electronic properties due to the σ -electron delocalization over the silicon framework (σ -conjugation), which is highly sensitive to the conformation of the silicon backbone.¹ Since the polysilane main chain has a random-coil structure without any constraint due to the low rotational barrier around the Si-Si single bond,² the relationship between the structure and the photophysical properties has not been elucidated until recently. The latest studies on a discrete conformer of oligosilanes revealed that the anti conformation, with a SiSiSiSi dihedral angle ω of 180°, is the most effective for the extension of the σ -conjugation. Thus, much effort has been made, including utilization of a cyclic³ or bicyclic⁴ structure, introduction of bulky⁵ or chiral^{6,7} substituents, incorporation of pentacoordinate silicon atoms,8 or inclusion into cyclodextrins,9,10 in order to control the silicon backbone conformation. Some of these approaches have indeed attained a close "all-anti" 11 conformation up to hexasilanes, but the development of a general method is still on the horizon.

As one of the potential building blocks for the ideal all-anti polysilane, we have designed a bis(tetramethylene)-tethered trisilane. Our preliminary study demonstrated that the *intra*-unit conformation is rigidly constrained to all-anti using the pentasilane comprising the bicyclic trisilane.¹² Herein we report the synthesis, structure, and UV absorption of the octasilane **8**, a trimethylsilyl-capped dimer of the trisilane unit. The *inter*-unit conformation of **8** has been successfully controlled to predominantly all-anti, even in solution at room temperature.

The synthetic route to the octasilane 8 is outlined in Scheme 1. The 1,3-diallyl-1,3-dichlorotrisilane 1^{12} was transformed into the isopropoxy-substituted trisilane 2. The bicyclic structure was constructed by ring-closing metathesis (RCM) using a 0.2 molar amount (m.a.) of the second-generation Grubbs catalyst (IMesRuCl2-(PCy₃)(=CHPh)),¹³ and subsequent hydrogenation of the internal olefin afforded the 1,3-diisopropoxy-substituted bicyclic trisilane 4. Compound 4 was transformed into the 1,3-dichlorotrisilane 6 by reaction with diisobutylaluminum hydride (DIBAH), followed by radical-induced chlorination on the terminal silicon atoms using carbon tetrachloride. The reductive condensation of 6 was attempted with lithium naphthalenide (LiNaph) in the presence of chlorotrimethylsilane, but this reaction afforded only the mono-trimethylsilyl-capped chlorotetrasilane 7 as the main product, together with a trace amount of the bis-trimethylsilyl-capped monomer (pentasilane) and dimer 8 (octasilane). The resulting chlorotetrasilane 7 was subjected to the reductive homo-coupling reaction using LiNaph to produce the target octasilane 8.

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Scheme 1. Preparation of Octasilane 8^a





The crystal structure of compound $\mathbf{8}$ was determined by an X-ray crystallographic analysis. The disordered structure was observed for the tetramethylene tethers. One of the structures with a higher occupancy is shown in Figure 1. As expected, eight silicon atoms



Figure 1. X-ray crystal structure of **8** (ORTEP drawing, 50% probability for thermal ellipsoids): (A) top view and (B) side view. Selected bond lengths (Å), bond angles (°), and torsion angles (°): Si(1)–Si(2) = 2.3562(9), Si(2)–Si(3) = 2.3419(8), Si(3)–Si(4) = 2.3534(8), Si(4)–Si(4*) = 2.3409(1), Si(1)–Si(2)–Si(3) = 112.43(3), Si(2)–Si(3)–Si(4) = 104.39(3), Si(3)–Si(4)–Si(4*) = 112.76(4), Si(1)–Si(2)–Si(3)–Si(4) = 179.85(3), Si(2)–Si(3)–Si(4)–Si(4*) = 180.

form the all-anti framework with the dihedral angles $\omega > 179.3^{\circ}$: not only the *intra*-unit but also the *inter*-unit conformations are successfully controlled exactly to anti in the crystal state. To the best of our knowledge, this is the longest all-anti oligosilane to date among the structurally defined ones.

The UV absorption spectra of octasilane **8** at 293 and 77 K are shown in Figure 2, and the data are summarized in Table 1, together



Figure 2. UV absorption spectra of 8 (red) and n-Si₈Me₁₈ (blue) in 3-methylpentane at 293 (solid line) and 77 K (dashed line).

Table 1. Summary of UV Absorption Spectra of 8 and n-Si₈Me₁₈^a

compound	293 K		77 K	
	λ_{max}/nm	<i>€</i> /10 ⁴	λ_{max}/nm	<i>€</i> /10 ⁴
8	288	10	287	21
n-Si ₈ Me ₁₈	274	3.4	281	15

^a All spectra were measured in 3-methylpentane.

with the data of *n*-Si₈Me₁₈¹⁴ for comparison. At 293 K, the absorption maximum of 8 corresponding to the lowest-energy $\sigma\sigma^*$ transition significantly shifts to a longer wavelength, and the extinction coefficient ϵ is 3 times greater than that of *n*-Si₈Me₁₈. These results demonstrate the effective extension of σ -conjugation in 8 and little deviation from the all-anti conformation due to the rigid trisilane unit even in a room-temperature solution, whereas the n-Si₈Me₁₈ has significant amount of rotational isomers at this temperature. Upon cooling of the sample to 77 K, the λ_{max} of *n*-Si₈-Me₁₈ red shifts by 7 nm, with a remarkable enhancement of the molar absorption coefficient, indicating that the thermodynamically most stable all-transoid11 conformation becomes predominant at the lower temperature.¹⁵ In sharp contrast, the primary band of the octasilane 8 showed only a slight blue shift, as seen in the oligosilanes with a rigid conformation.¹⁴ The small shift in λ_{max} of 8 indicates that the all-anti conformation is predominant for 8, even at room temperature.

Calculations have been performed to analyze the conformation, and the ground-state potential energy of 8 was drawn as a function of the inter-unit SiSiSiSi dihedral angle ω (Supporting Information). It was found that the point at $\omega = 180^{\circ}$ corresponds to the global minimum, and a shallow potential valley centered around $\omega \approx \pm 50^{\circ}$ lies ca. 3 kcal/mol higher in energy. This result is not discouraging, because even a pentasilane, $n-Si_5Me_{12}$, is reported to have nine stable conformers other than all-transoid within 3 kcal/mol (at HF/ $3-21G^*$ level),^{16a} and thus *n*-Si₈Me₁₈ should have much more. In contrast, the silicon chain of the octasilane 8 is predominantly controlled to all-anti, and only one conformational isomer exists since there is only one Si-Si bond that allows twisting about it.

Another outstanding point of this molecular design is that the energy minimum appears at the anti limit with exactly $\omega = 180^{\circ}$, not transoid with $\omega \approx \pm 165^\circ$, as seen in the permethylated oligosilanes n-Si_nMe_{2n+2}. The origin of the transoid conformer of $n-Si_nMe_{2n+2}$ is the 1,3-steric repulsion between the methyl groups.^{16b} Between our bicyclic trisilane units, such a repulsion is reduced due to tethering of the tetramethylenes, thus keeping the rotational barrier almost unchanged, which produces the two-isomer system similar to n-Si₄H₁₀. These results clearly demonstrate the practical significance of the bicyclic trisilane unit as a powerful building block to attain the longer all-anti polysilane, an ideal σ -conjugated system.

In summary, we have synthesized the octasilane 8 composed of two bicyclic trisilane units with trimethylsilyl groups at the termini. Its X-ray crystal structure and the spectroscopic data demonstrate the effective σ -delocalization over the silicon framework, which is a definitive difference from the unconstrained $n-Si_8Me_{18}$. More detailed spectroscopic studies, such as photoluminescence, as well as the preparation of longer oligo- and polysilanes having bicyclic trisilane units are now under investigation.

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Supporting Information Available: Experimental details, spectral data, crystallographic data, and results of theoretical calculations for the ground-state potential energy of 8 (PDF, CIF). This material is available free of charge via the Internet at http://pubs.acs.org.

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